

Optocoupler, Phototransistor Output, Low Input Current, With Base Connection, 5300 V_{RMS}

Features

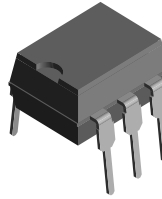
- Very High CTR at $I_F = 1.0 \text{ mA}$, $V_{CE} = 0.5 \text{ V}$
- Specified Minimum CTR at $I_F = 0.5 \text{ mA}$,
- $V_{CE} = 1.5 \text{ V} \geq 32 \%$ (typ. 120 %)
- Good CTR Linearity with Forward Current
- Low CTR Degradation
- High Collector-Emitter Voltage $V_{CEO} = 55 \text{ V}$
- Isolation Test Voltage: 5300 V_{RMS}
- Low Current Input
- Low Coupling Capacitance
- High Common Mode Transient Immunity
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- DIN EN 60747-5-2 (VDE0884)
DIN EN 60747-5-5 pending
Available with Option 1
- CSA 93751
- BSI IEC60950 IEC60065

Applications

Telecommunications
Industrial Controls
Office Machines
Microprocessor System Interfaces



1179004



Description

The SFH 608 is an optocoupler designed for high current transfer ratio at low input currents with the output transistor saturated. This makes the device ideal for low current switching applications. The SFH608 is packaged in a six pin plastic DIP.

Order Information

| Part | Remarks |
|---------------|---|
| SFH608-2 | CTR 63 - 125 %, DIP-6 |
| SFH608-3 | CTR 100 - 200 %, DIP-6 |
| SFH608-4 | CTR 160 - 320 %, DIP-6 |
| SFH608-5 | CTR 250 - 500 %, DIP-6 |
| SFH608-2-X006 | CTR 63 - 125 %, DIP-6 400 mil (option 6) |
| SFH608-2-X007 | CTR 63 - 125 %, SMD-6 (option 7) |
| SFH608-2-X009 | CTR 63 - 125 %, SMD-6 (option 9) |
| SFH608-3-X006 | CTR 100 - 200 %, DIP-6 400 mil (option 6) |
| SFH608-3-X007 | CTR 100 - 200 %, SMD-6 (option 7) |
| SFH608-4-X006 | CTR 160 - 320 %, DIP-6 400 mil (option 6) |
| SFH608-4-X007 | CTR 160 - 320 %, SMD-6 (option 7) |
| SFH608-5-X007 | CTR 250 - 500 %, SMD-6 (option 7) |

For additional information on the available options refer to Option Information.

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

Input

| Parameter | Test condition | Symbol | Value | Unit |
|-------------------------|--------------------------------|------------|-------|------|
| Reverse voltage | | V_R | 6.0 | V |
| DC Forward current | | I_F | 50 | mA |
| Surge forward current | $t \leq 10\text{ }\mu\text{s}$ | I_{FSM} | 2.5 | A |
| Total power dissipation | | P_{diss} | 70 | mW |

Output

| Parameter | Test condition | Symbol | Value | Unit |
|---------------------------|--------------------------|------------|-------|------|
| Collector-emitter voltage | | V_{CE} | 55 | V |
| Collector-base voltage | | V_{CBO} | 55 | V |
| Emitter-base voltage | | V_{EBO} | 7.0 | V |
| Collector current | | I_C | 50 | mA |
| Surge collector current | $t_p \leq 1.0\text{ ms}$ | | 100 | mA |
| Total power dissipation | | P_{diss} | 150 | mW |

Coupler

| Parameter | Test condition | Symbol | Value | Unit |
|--|--|-----------|----------------|--------------------|
| Isolation test voltage (between emitter and detector, refer to climate DIN 40046 part 2 Nov. 74) | $t = 1.0\text{ s}$ | V_{ISO} | 5300 | V_{RMS} |
| Creepage | | | ≥ 7.0 | mm |
| Clearance | | | ≥ 7.0 | mm |
| Comparative tracking index per DIN IEC 112/VDE 0303, part 1 | | | 175 | |
| Isolation resistance | $V_{IO} = 500\text{ V}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$ | R_{IO} | $\geq 10^{12}$ | Ω |
| | $V_{IO} = 500\text{ V}$, $T_{amb} = 100\text{ }^{\circ}\text{C}$ | R_{IO} | $\geq 10^{11}$ | Ω |
| Storage temperature range | | T_{stg} | - 55 to + 150 | $^{\circ}\text{C}$ |
| Operating temperature range | | T_{amb} | - 55 to + 100 | $^{\circ}\text{C}$ |
| Soldering temperature | max. 10 s, dip soldering: distance to seating plane $\geq 1.5\text{ mm}$ | T_{sld} | 260 | $^{\circ}\text{C}$ |

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

Input

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|--------------------|---|------------|-----|------|-----|---------------|
| Forward voltage | $I_F = 5.0\text{ mA}$ | V_F | | 1.1 | 1.5 | V |
| Reverse voltage | $I_R = 10\text{ }\mu\text{A}$ | V_R | 6.0 | | | V |
| Reverse current | $V_R = 6.0\text{ V}$ | I_R | | 0.01 | 10 | μA |
| Capacitance | $V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$ | C_O | | 25 | | pF |
| Thermal resistance | | R_{thja} | | 1070 | | K/W |

Output

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|-----------------------------------|---------------------------------------|------------|-----|------|-----|------|
| Voltage, collector-emitter | $I_{CE} = 10\text{ }\mu\text{A}$ | V_{CEO} | 55 | | | V |
| Voltage, emitter-base | $I_{EB} = 10\text{ }\mu\text{A}$ | V_{EBO} | 7.0 | | | V |
| Collector-emitter capacitance | $V_{CE} = 5.0$, $f = 1.0\text{ MHz}$ | C_{CE} | | 10 | | pF |
| Collector - base capacitance | $V_{CE} = 5.0$, $f = 1.0\text{ MHz}$ | C_{CB} | | 16 | | pF |
| Emitter - base capacitance | $V_{CE} = 5.0$, $f = 1.0\text{ MHz}$ | C_{EB} | | 10 | | pF |
| Thermal resistance | | R_{thja} | | 500 | | K/W |
| Collector-emitter leakage current | $V_{CE} = 10\text{ V}$ | I_{CEO} | | 10 | 200 | nA |

Coupler

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|---------------------------------------|---|----------|-------------|-----|------|-----|------|
| Coupling capacitance | | | C_C | | 0.60 | | pF |
| Saturation voltage, collector-emitter | $I_C = 0.32\text{ mA}$, $I_F = 1.0\text{ mA}$ | SFH608-2 | V_{CEsat} | | 0.25 | 0.4 | V |
| | $I_C = 0.5\text{ mA}$, $I_F = 1.0\text{ mA}$ | SFH608-3 | V_{CEsat} | | 0.25 | 0.4 | V |
| | $I_C = 0.8\text{ mA}$, $I_F = 1.0\text{ mA}$ | SFH608-4 | V_{CEsat} | | 0.25 | 0.4 | V |
| | $I_C = 0.125\text{ mA}$, $I_F = 1.0\text{ mA}$ | SFH608-5 | V_{CEsat} | | 0.25 | 0.4 | V |

Current Transfer Ratio

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|-------------------------|---|----------|--------|-----|------|-----|------|
| Coupling Transfer Ratio | $I_F = 1.0\text{ mA}$, $V_{CE} = 0.5\text{ V}$ | SFH608-2 | CTR | 63 | | 125 | % |
| | $I_F = 0.5\text{ mA}$, $V_{CE} = 1.5\text{ V}$ | SFH608-2 | CTR | 32 | 75 | | % |
| | $I_F = 1.0\text{ mA}$, $V_{CE} = 0.5\text{ V}$ | SFH608-3 | CTR | 100 | | 200 | % |
| | $I_F = 0.5\text{ mA}$, $V_{CE} = 1.5\text{ V}$ | SFH608-3 | CTR | 50 | 120 | | % |
| | $I_F = 1.0\text{ mA}$, $V_{CE} = 0.5\text{ V}$ | SFH608-4 | CTR | 160 | | 320 | % |
| | $I_F = 0.5\text{ mA}$, $V_{CE} = 1.5\text{ V}$ | SFH608-4 | CTR | 80 | 200 | | % |
| | $I_F = 1.0\text{ mA}$, $V_{CE} = 0.5\text{ V}$ | SFH608-5 | CTR | 250 | | 500 | % |
| | $I_F = 0.5\text{ mA}$, $V_{CE} = 1.5\text{ V}$ | SFH608-5 | CTR | 125 | 300 | | % |

Switching Characteristics

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|---------------|--|-----------|-----|------|-----|---------------|
| Turn-on time | $I_C = 2.0 \text{ mA}$ (to adjust by I_F), $R_L = 100 \Omega$, $V_{CC} = 5.0 \text{ V}$ | t_{on} | | 8.0 | | μs |
| Rise time | $I_C = 2.0 \text{ mA}$ (to adjust by I_F), $R_L = 100 \Omega$, $V_{CC} = 5.0 \text{ V}$ | t_r | | 5.0 | | μs |
| Turn-off time | $I_C = 2.0 \text{ mA}$ (to adjust by I_F), $R_L = 100 \Omega$, $V_{CC} = 5.0 \text{ V}$ | t_{off} | | 7.5 | | μs |
| Fall time | $I_C = 2.0 \text{ mA}$ (to adjust by I_F), $R_L = 100 \Omega$, $V_{CC} = 5.0 \text{ V}$ | t_f | | 7.0 | | μs |

Typical Characteristics ($T_{amb} = 25 \text{ }^\circ\text{C}$ unless otherwise specified)



Figure 1. Switching Schematic

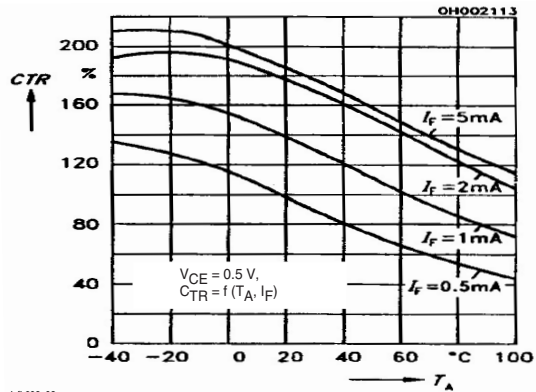


Figure 3. Current Transfer Ratio (typ.)

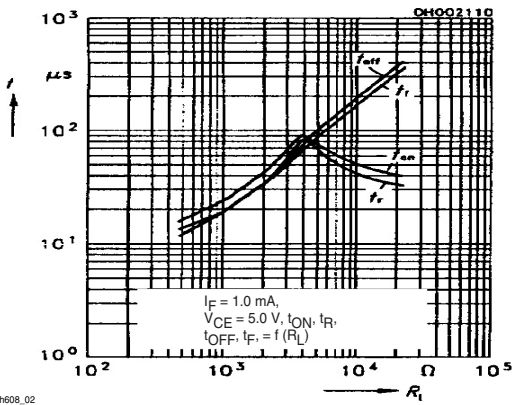


Figure 2. Switching Times

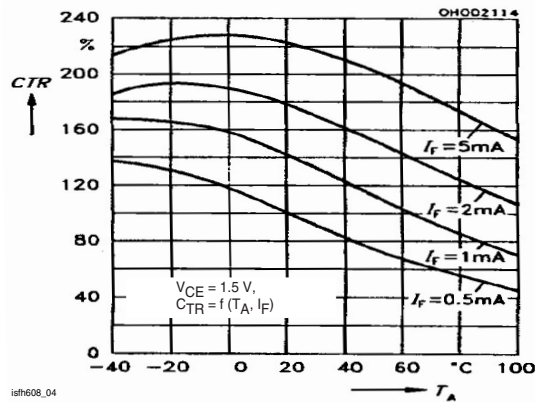


Figure 4. Current Transfer Ratio (typ.)



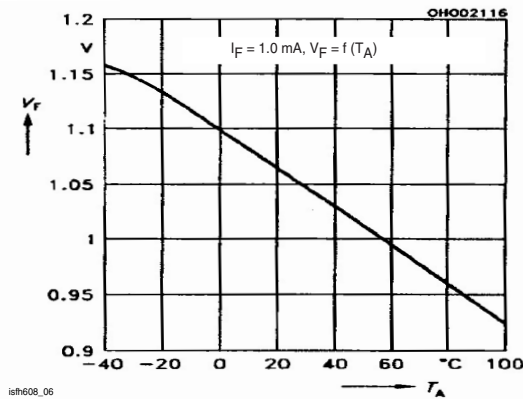
isth608_05

Figure 5. Diode Forward Voltage (typ.)



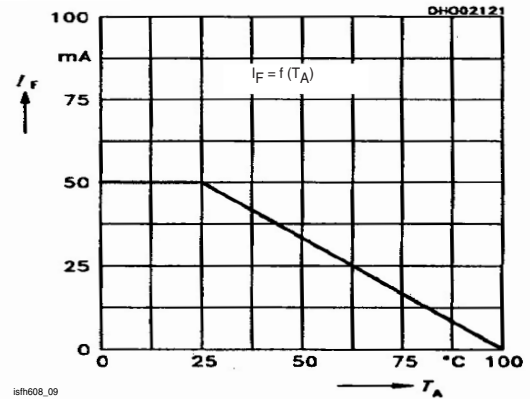
isth608_08

Figure 8. Output Characteristics



isth608_06

Figure 6. Diode Forward Voltage (typ.)



isth608_09

Figure 9. Permissible Forward Current Diode



isth608_07

Figure 7. Output Characteristics



isth608_10

Figure 10. Permissible Power Dissipation for Transistor and Diode

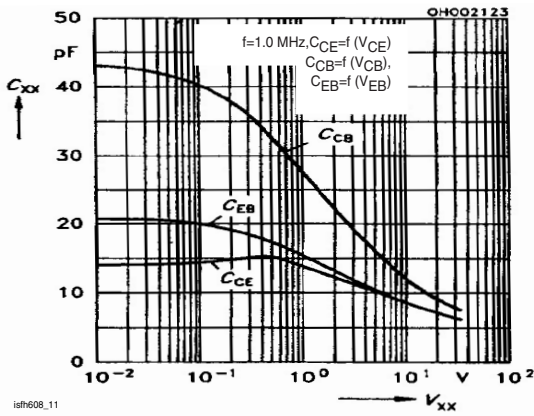


Figure 11. Transistor Capacitance

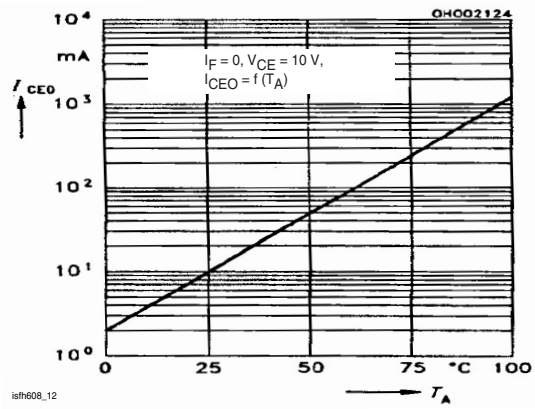
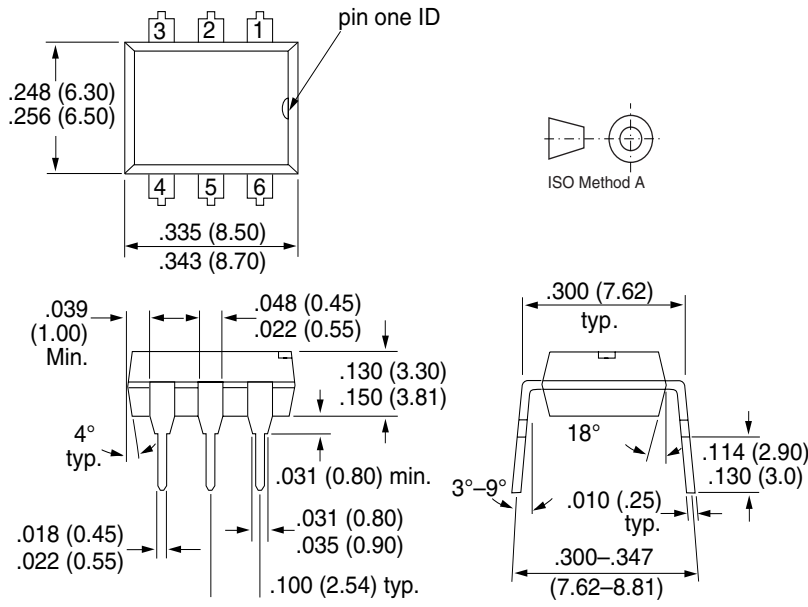


Figure 12. Collector-Emitter Leakage Current vs. Temp.

Package Dimensions in Inches (mm)



i178004

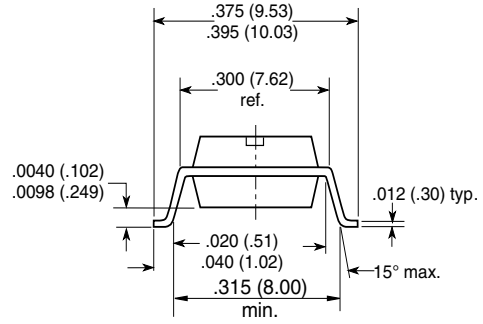
Option 6



Option 7



Option 9



18450

Ozone Depleting Substances Policy Statement

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1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

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2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423



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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А